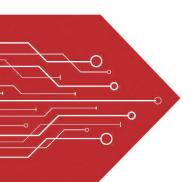
# MSKSEMI















**ESD** 

TVS

**TSS** 

MOV

**GDT** 

**PLED** 

# Broduct data sheet



### DIGITAL TRANSISTOR (NPN)

#### **FEATURES**

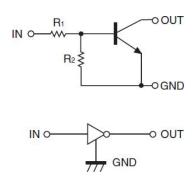
- Built-in bias resistors enable the

  configuration of an inverter circuit without

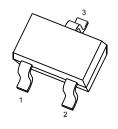
  connecting external input resistors(see equivalent circuit)
- The bias resistors consist of thin-film resistors
   with complete isolation to allow negative biasing
   of the input. They also have the advantage of almost completely
   eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy



## Equivalent Circuit



#### · PIN

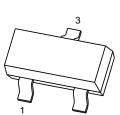


**SOT-323** 

IN
 GND

3. OUT

DTC143EUA-MS



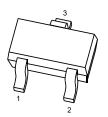
DTC143ECA-MS

1. IN

2. GND

3. OUT

SOT-23

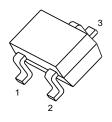


1. IN

2. GND

3. OUT

DTC143EE-MS SOT-523



1. IN

2. GND

3. OUT

DTC143EKA-MS SOT-23-3L



# MAXIMUM RATINGS(Ta=25℃ unless otherwise noted)

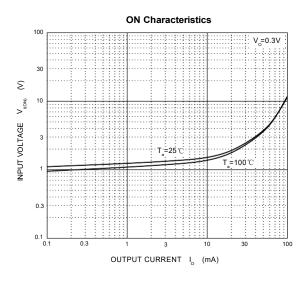
Symbol	Parameter	DTC143				Unit			
Cymbol	raidiffeter		EE-MS	EUA-MS	ECA-MS	EKA-MS			
V <sub>cc</sub>	Supply Voltage	50			V				
V <sub>IN</sub>	Input Voltage	-10∼+30				V			
lo	Output Current	100				mA			
P <sub>D</sub>	Power Dissipation		150	200	200	200		mW	
Tj	Junction Temperature	150		$^{\circ}$					
T <sub>stg</sub>	Storage Temperature	-55∼+150		$^{\circ}$					

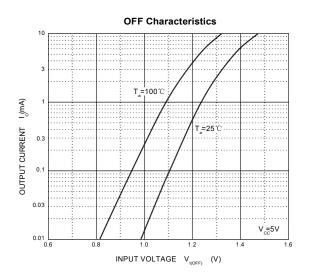
# **ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)**

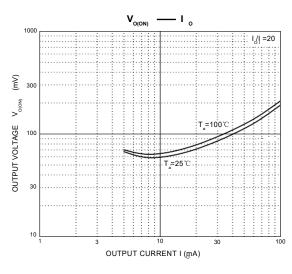
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Input voltage	V <sub>I(off)</sub>	V <sub>CC</sub> =5V,I <sub>O</sub> =100μA	0.5			V
Input voltage	V <sub>I(on)</sub>	Vo=0.3V,Io=20mA			3	V
Output voltage	V <sub>O(on)</sub>	I <sub>O</sub> /I <sub>I</sub> =10mA/0.5mA			0.3	V
Input current	I	V <sub>I</sub> =5V			1.8	mA
Output current	I <sub>O(off)</sub>	V <sub>CC</sub> =50V,V <sub>I</sub> =0			0.5	μA
DC current gain	Gı	V <sub>O</sub> =5V,I <sub>O</sub> =10mA	20			
Input resistance	R <sub>1</sub>		3.29	4.7	6.11	kΩ
Resistance ratio	R <sub>2</sub> /R <sub>1</sub>		0.8	1	1.2	
Transition frequency	f⊤	V <sub>0</sub> =10V,I <sub>0</sub> =5mA,f=100MHz		250		MHz

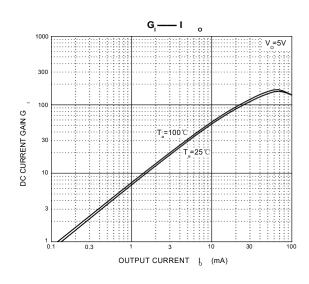


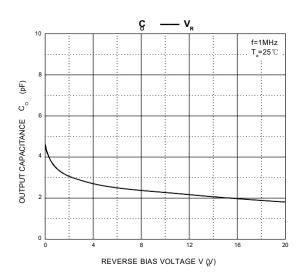
# **Typical Characteristics**

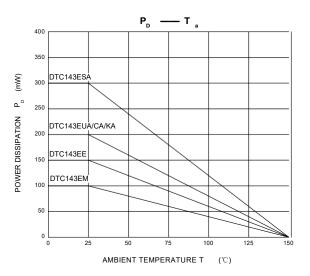




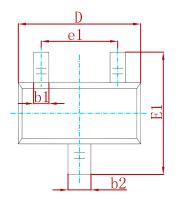


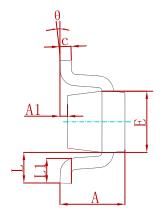


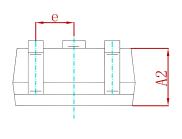






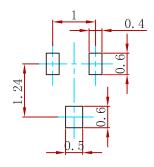






Comple ed	Dimensions	In Millimeters Dimensions I		s In Inches
Symbol	Min.	Max.	Min.	Max.
Α	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
С	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
е	0.500	TYP.	0.020	TYP.
e1	0.900	1.100	0.035	0.043
L	0.400	REF.	0.016	REF.
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

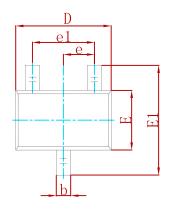
# Suggested Pad Layout

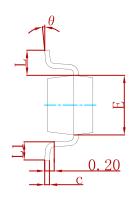


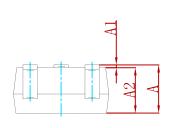
- 1.Controlling dimension:in millimeters.2.General tolerance:±0.05mm.3.The pad layout is for reference purposes only.

P/N	PKG	QTY
DTC143EE-MS	SOT-523	3000



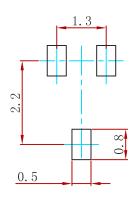






Symbol	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
Α	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.200	0.400	0.008	0.016
С	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
Е	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
е	0.650	) TYP	0.026	6 TYP
e1	1.200	1.400	0.047	0.055
L	0.525	REF	0.021	REF
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

# **Suggested Pad Layout**

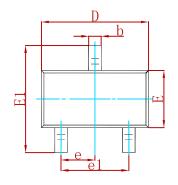


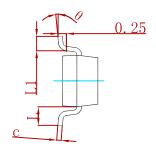
#### Note:

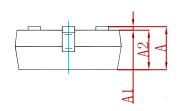
- 1. Controlling dimension:in millimeters.
- 2.General tolerance:±0.05mm.
- 3. The pad layout is for reference purposes only.

P/N	PKG	QTY
DTC143EUA-MS	SOT-323	3000



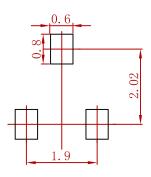






Symbol	Dimensions	In Millimeters	Dimension	s In Inches
Symbol	Min	Max	Min	Max
Α	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
С	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
Е	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
е	0.950	) TYP	0.037	7 TYP
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022	2 REF
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

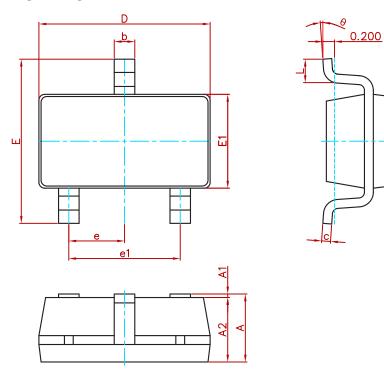
# **Suggested Pad Layout**



- 1.Controlling dimension:in millimeters.2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

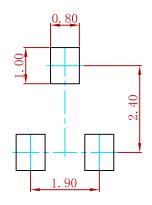
P/N	PKG	QTY
DTC143ECA-MS	SOT-23	3000





Symbol	Dimensions In	n Millimeters	Dimension	s In Inches
Symbol	Min.	Max.	Min.	Max.
Α	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
С	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E1	1.500	1.700	0.059	0.067
E	2.650	2.950	0.104	0.116
е	0.950(	BSC)	0.037(	(BSC)
e1	1.800	2.000	0.071	0.079
L	0.300	0.600	0.012	0.024
θ	0°	8°	0°	8°

# **Suggested Pad Layout**



- 1.Controlling dimension:in millimeters.
- 2.General tolerance:± 0.05mm.3.The pad layout is for reference purposes only.

P/N	PKG	QTY
DTC143EKA-MS	SOT-23-3L	3000



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